

#### Description

The AP8205S uses advanced trench technology

to provide excellent RDS(ON), low gate charge

and operation with gate voltages as low as 2.5V.

This device is suitable for use as a Battery

protection or in other Switching application.



 $V_{DS} = 20V, I_{D} = 6A$ 

 $R_{DS(ON)}$  < 20.5.m $\Omega$  @ V<sub>GS</sub>=4.5V

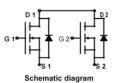
 $R_{DS(ON)}$  < 27.m $\Omega$  @ Vgs=2.5V

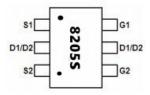
#### **Application**

Battery protection

Load switch

Powermanagement







#### **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
AP8205S	SOT-23-6L	8205S	3000

## Absolute Maximum Ratings@T<sub>j</sub>=25°C(unless otherwise specified)

Symbol	Parameter	Rating	Units
V <sub>DS</sub>	Drain-Source Voltage	20	V
V <sub>G</sub> S	Gate-Source Voltage	<u>+</u> 12	V
I <sub>D</sub> @T <sub>A</sub> =25°C	Drain Current, V <sub>GS</sub> @ 4.5V <sup>3</sup>	6	А
I <sub>D</sub> @T <sub>A</sub> =70°C	Drain Current, V <sub>GS</sub> @ 4.5V <sup>3</sup>	4.8	А
IDM	Pulsed Drain Current <sup>1</sup>	26	А
P <sub>D</sub> @T <sub>A</sub> =25°C	Total Power Dissipation	2	W
	Linear Derating Factor	0.016	W/°C
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
Rthj-a	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	62.5	°C/W



# Electrical Characteristics@T<sub>j</sub>=25°C(unless otherwise specified)

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Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	_	-	V
RDS(ON)	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A	-	20.5	27	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4A	-	27	37	mΩ
VGS(th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	-	0.75	1.2	V
<b>G</b> fs	Forward Transconductance	V <sub>DS</sub> =10V, I <sub>D</sub> =6A	-	6	_	S
IDSS	Drain-Source Leakage Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	25	uA
	Drain-Source Leakage Current (T <sub>j</sub> =70°C)	V <sub>DS</sub> =20V ,V <sub>GS</sub> =0V	-	-	250	uA
IGSS	Gate-Source Leakage	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Qg	Total Gate Charge <sup>2</sup>	I <sub>D</sub> =6A	-	11	17.6	nC
Qgs	Gate-Source Charge	V <sub>DS</sub> =16V	-	1.1	-	nC
$Q_{gd}$	Gate-Drain ("Miller") Charge	V <sub>GS</sub> =4.5V	-	4.1	-	nC
td(on)	Turn-on Delay Time <sup>2</sup>	V <sub>DS</sub> =10V	-	4.2	-	ns
t <sub>r</sub>	Rise Time	I <sub>D</sub> =1A	-	9	-	ns
td(off)	Turn-off Delay Time	R <sub>G</sub> =3.3Ω,V <sub>GS</sub> =10V	-	23	-	ns
t <sub>f</sub>	Fall Time	R <sub>D</sub> =10Ω	-	3.5	-	ns
Ciss	Input Capacitance	V <sub>GS</sub> =0V	-	570	910	pF
Coss	Output Capacitance	V <sub>DS</sub> =20V	_	90	-	pF
Crss	Reverse Transfer Capacitance	f=1.0MHz	-	85	-	pF
R <sub>g</sub>	Gate Resistance	f=1.0MHz	-	1.6	2.4	Ω
V <sub>SD</sub>	Forward On Voltage <sup>2</sup>	Is=1.7A, V <sub>GS</sub> =0V	-	-	1.2	V
trr	Reverse Recovery Time <sup>2</sup>	Is=6A, V <sub>GS</sub> =0V, dI/dt=100A/μs	-	21	-	ns
Qrr	Reverse Recovery Charge		-	14	-	nC

<sup>1.</sup> Pulse width limited by Max. junction temperature.

<sup>2.</sup>Pulse test

<sup>3.</sup>Surface mounted on 1 in 2 copper pad of FR4 board, t  $\leq$ 10sec ; 135 °C/W when mounted on Min. copper pad.



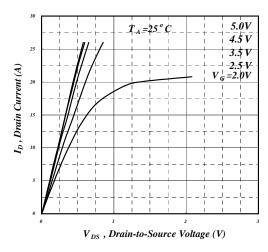


Fig 1. Typical Output Characteristics

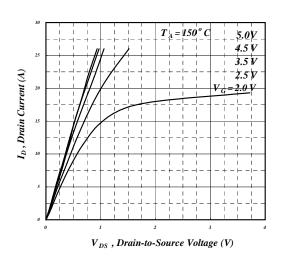


Fig 2. Typical Output Characteristics

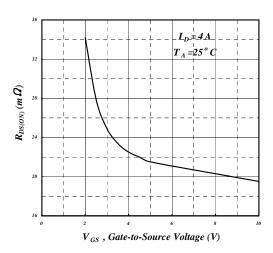


Fig 3. On-Resistance v.s. Gate Voltage

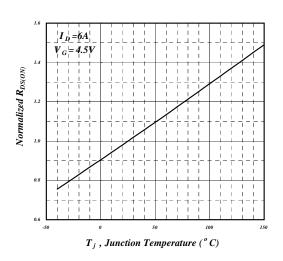


Fig 4. Normalized On-Resistance v.s. Temperature

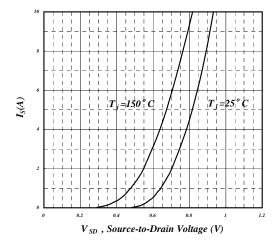


Fig 5. Forward Characteristic of Reverse Diode

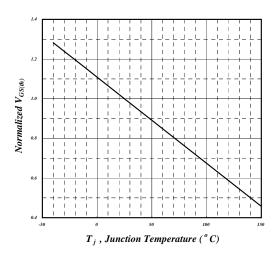


Fig 6. Gate Threshold Voltage v.s.
Junction Temperature





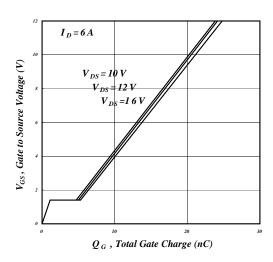


Fig 7. Gate Charge Characteristics

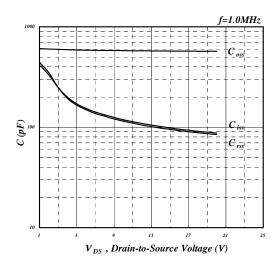


Fig 8. Typical Capacitance Characteristics

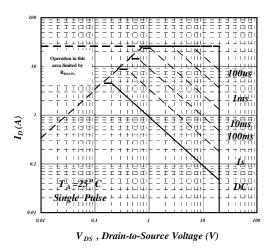


Fig 9. Maximum Safe Operating Area

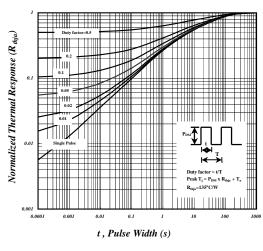


Fig 10. Effective Transient Thermal Impedance

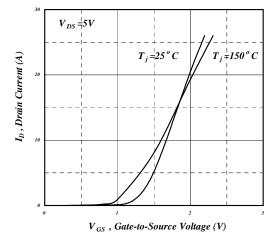


Fig 11. Transfer Characteristics

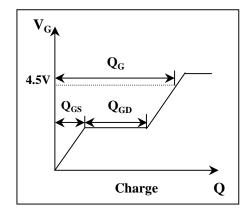
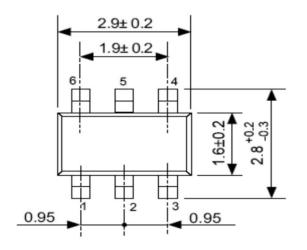
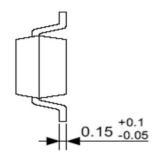


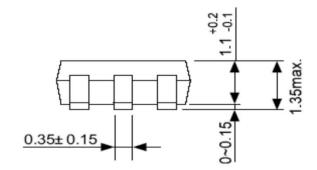
Fig 12. Gate Charge Waveform



## **SOT23-6 PACKAGE INFORMATION**









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